

FDPF3N50NZ N-Channel UniFETTM II MOSFET 500 V, 3 A, 2.5 Ω

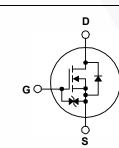
Features

- $R_{DS(on)} = 2.1 \Omega (Typ.) @ V_{GS} = 10 V, I_D = 1.5 A$
- Low Gate Charge (Typ. 6.2 nC)
- Low C_{rss} (Typ. 2.5 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- · ESD Improved Capability
- RoHS Compliant

Applications

- LCD/LED TV
- Uninterruptible Power Supply
- Lighting
- AC-DC Power Supply





Description

lasts.

MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Parameter			FDPF3N50NZ	Unit	
Drain to Source Voltage			500	V	
Gate to Source Voltage			±25	V	
Desia Current	- Continuous ($T_C = 25^{\circ}C$)		3*		
Drain Current	- Continuous (T _C = 100 ^o C)	1.8*	— A	
Drain Current	- Pulsed	(Note 1)	12*	A	
Single Pulsed Avalanche Energy		(Note 2)	113	mJ	
Avalanche Current		(Note 1)	3	Α	
Repetitive Avalanche Energy		(Note 1)	5.4	mJ	
Peak Diode Recovery dv/dt		(Note 3)	10	V/ns	
Deven Dia dia atian	(T _C = 25 ^o C)		27	W	
Power Dissipation	- Derate above 25ºC		0.21	W/ºC	
Operating and Storage Temperature Range			-55 to +150	°C	
Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	
	Gate to Source Voltage Drain Current Drain Current Single Pulsed Avalanch Avalanche Current Repetitive Avalanche En Peak Diode Recovery de Power Dissipation Operating and Storage Maximum Lead Temper	$\begin{tabular}{ c c c c } \hline Drain to Source Voltage & & & & & & & & & & & & & & & & & & &$	$\begin{tabular}{ c c c c } \hline \end{tabular} & \begin{tabular}{ c c c c } \hline \end{tabular} \\ \hline tab$	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	

Thermal Characteristics

Symbol	Parameter	FDPF3N50NZ	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	4.6	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/vv

October 2013

UniFETTM II MOSFET is Fairchild Semiconductor's high voltage

MOSFET family based on advanced planar stripe and DMOS

technology. This advanced MOSFET family has the smallest

on-state resistance among the planar MOSFET, and also pro-

vides superior switching performance and higher avalanche

energy strength. In addition, internal gate-source ESD diode allows UniFET II MOSFET to withstand over 2kV HBM surge

stress. This device family is suitable for switching power con-

verter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp bal-

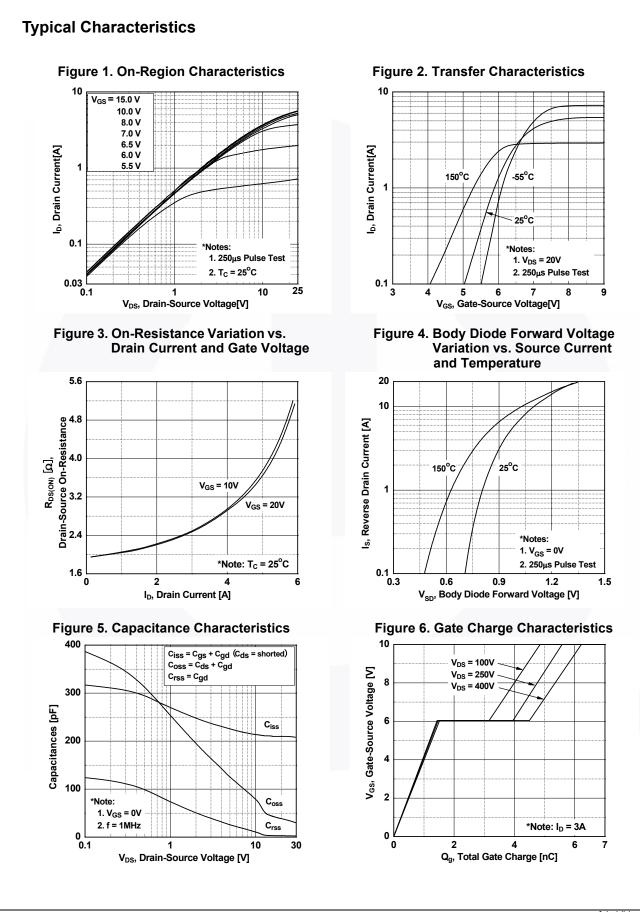


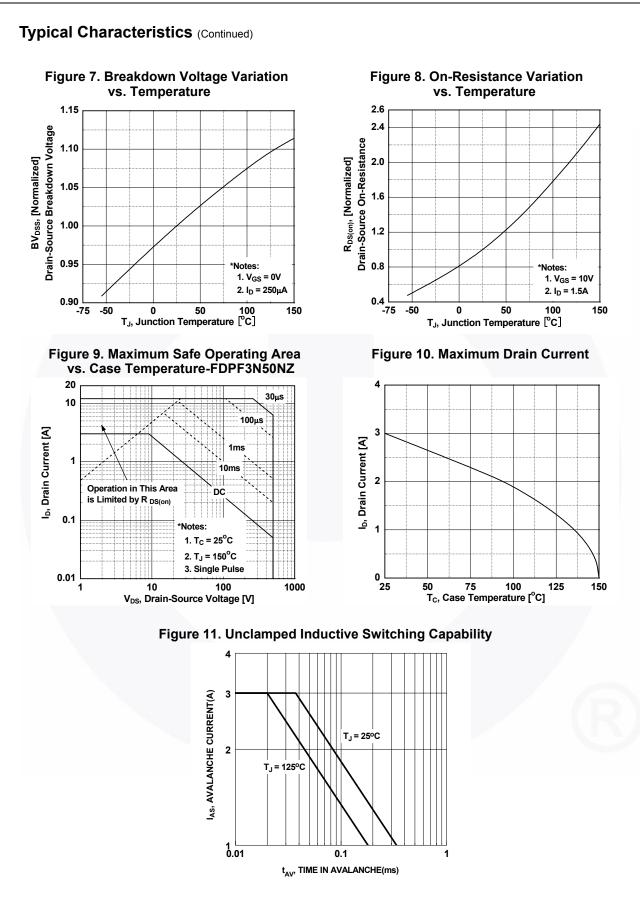
_		Pack	age	Reel Size	Тар	e Width		Quantit	y	
		TO-22				N/A		50 units		
Electrica	al Char	acteristics T _c =	25°C unles	s otherwis	se noted					
Symbol		Parameter			Test Condition	ns	Min.	Тур.	Max.	Unit
Off Chara	cteristic	s								
BV _{DSS}		Source Breakdown V	oltage	lp = 25	$50\mu A V_{CC} = 0V T$	$c = 25^{\circ}C$	500	_	-	V
∆BV _{DSS}	Breakdown Voltage Temperature Coefficient		0	I _D = 250μA, V _{GS} = 0V, T _C = 25 ^o C		500		_		
$/\Delta T_J$				I _D = 25	60μA, Referenced	to 25°C	-	0.5	-	V/°C
		ate Voltage Drain Current		$V_{DS} = 500V, V_{GS} = 0V$ $V_{DS} = 400V, V_{GS} = 0V, T_{C} = 125^{\circ}C$		-	-	1		
						-	-	10	μΑ	
I _{GSS}	Gate to Body Leakage Current		ıt	V _{GS} =	±25V, V _{DS} = 0V		-	-	±10	μA
On Charad	cteristic	s								
V _{GS(th)}	Gate TI	nreshold Voltage		V _{GS} =	V _{DS} , I _D = 250μA		3.0	-	5.0	V
R _{DS(on)}		rain to Source On Res	sistance		10V, I _D = 1.5A		-	2.1	2.5	Ω
9 _{FS}	Forwar	d Transconductance			20V, I _D = 1.5A		-	1.9	-	S
Dynamic (C _{iss}	Input C	apacitance	Vpc = 25V V		25V, V _{GS} = 0V		-	210	280	pF
C _{oss}		Capacitance	_	f = 1MHz		-	30	45	pF	
C _{rss}		e Transfer Capacitance	9			-	2.5	5	pF	
Q _{g(tot)}		ate Charge at 10V	_			-	6.2	9	nC	
Q _{gs}	Gate to	Source Gate Charge	_	$V_{DS} = V_{GS} =$	400V I _D = 3A 10V	-	-	1.4	-	nC
Q _{gd}	Gate to	Drain "Miller" Charge		• GS		(Note 4)	-	3.1	-	nC
Switching	Charac	teristics								
t _{d(on)}	Turn-Or	n Delay Time	-			-	10	30	ns	
t _r	Turn-Or	n Rise Time		V _{DD} =	250V, I _D = 3A		-	15	40	ns
	Turn-Of	f Delay Time		V_{GS} = 10V, R_{GEN} = 25 Ω		-	26	60	ns	
t _{d(off)}	Turn-Of	f Fall Time				(Note 4)	-	17	45	ns
t _{d(off)} t _f			_							
t _f	rce Dio	de Characteristic	S						2	Α
t _f Drain-Sou		de Characteristic m Continuous Drain to		de Forwa	rd Current		-	-	3	
brain-Sou	Maximu		Source Dic				-	-	12	A
t _f Drain-Sou I _S I _{SM}	Maximu Maximu	m Continuous Drain to	Source Dic Irce Diode F	orward C			-	-		
t _f	Maximu Maximu Drain to	m Continuous Drain to m Pulsed Drain to Sou	Source Dic Irce Diode F	orward C V _{GS} =	urrent			- - - 190	12	Α

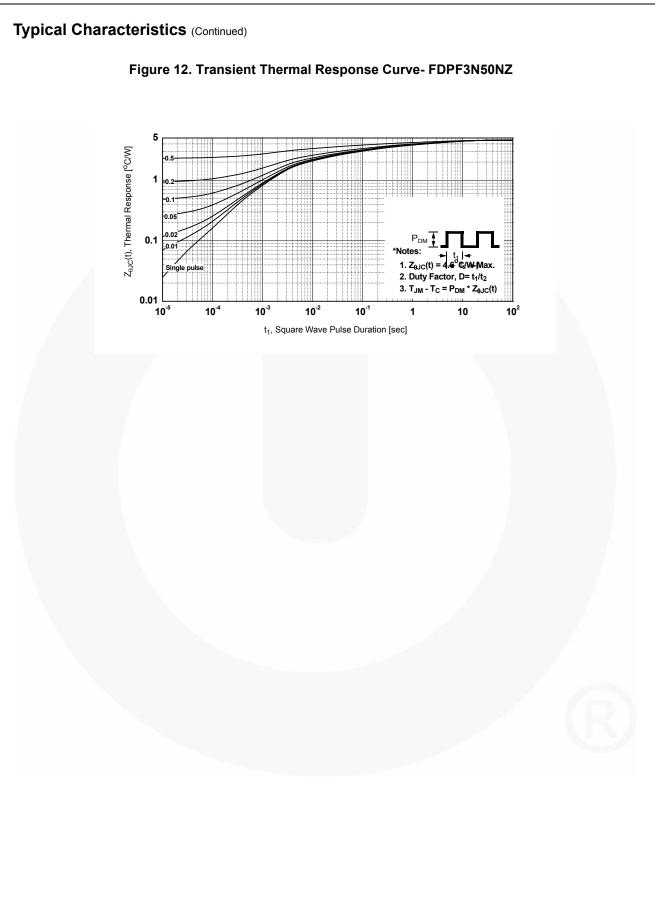
3. $I_{SD} \le 3A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

4. Essentially Independent of Operating Temperature Typical Characteristics

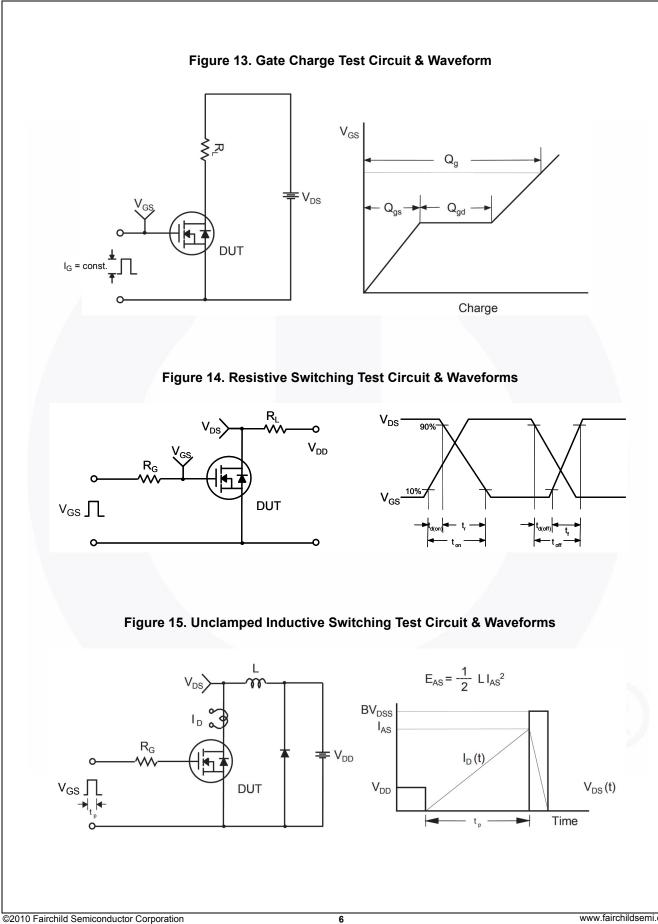
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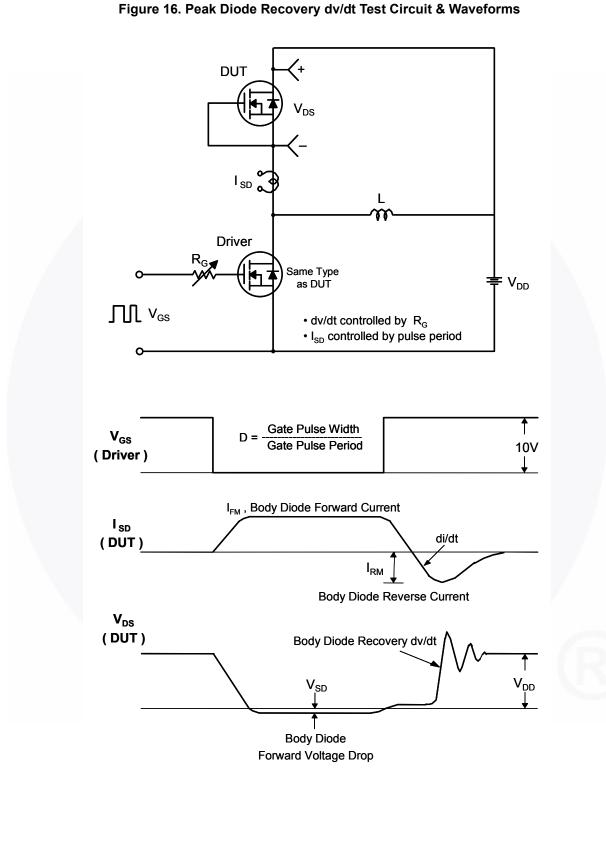


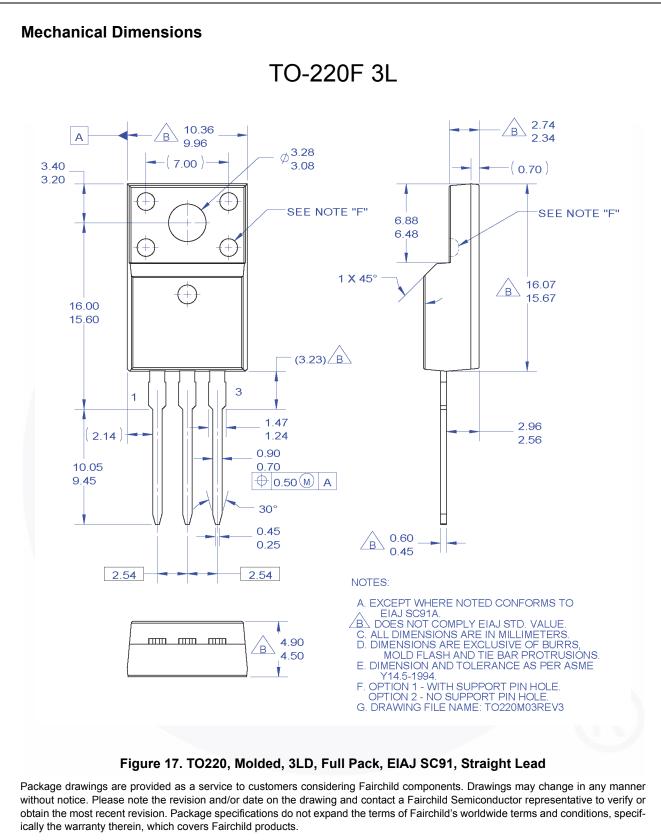




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Dimension in Millimeters

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